Research Article

Regrowth of Carbon Nanotubes Array on Al Layer Coated Substrate

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Carbon nanotube (CNT) arrays have been synthesized by a repeated growth method using a custom-fabricated plasma-enhanced thermal chemical vapor deposition (PE-thermal CVD) apparatus. The initial catalyst is a layered structure prepared by depositing 10 nm of Al followed by 3 nm of Fe on an oxidized silicon substrate. Following CNT growth, the CNT arrays are removed using an ultrasonic cleaner, and another CNT array is grown on the remaining Fe-Al bimetallic nanoparticles without the addition of more catalyst. Annealing the catalytic substrate in air between growth cycles results in the removal of residual amorphous carbon along with the CNTs, and oxidation of the Fe-Al nanoparticles. The diameter of CNTs is reduced with repeated growth-annealing cycles, an effect of which is attributed to the diminishing size of the catalytically active nanoparticles with each cycle. After two growth cycles, SWNTs with the extraordinarily narrow diameter of 0.86 nm are synthesized. The $I_D/I_G$ ratio derived from the Raman spectrum of these SWNT arrays shows the remarkably low value of 0.22.

1. Introduction

Multi-walled carbon nanotubes (MWNTs) array [1, 2] has attracted increased attention because of its potential applications in gas sensor [3, 4], field emitter [5, 6] and ballistic devices [7–9]. The peculiar properties of single-walled carbon nanotubes (SWNTs) [10–12] have also been regarded as one of the high-potential material for nano-devices. Thus, the SWNT array has recently gathered much attention. Control of size and density of catalytic particles is one of important factors for the fabrication of the SWNT array by chemical vapor deposition (CVD).

It is generally accepted that CNTs grow as carbon precipitates from supersaturated catalytic metal nanoparticles. The growth mechanisms are classified into base growth or tip growth, depending on whether the metal and nano-particle remains anchored at the support or not [13]. In a previous work [14], we demonstrated that the two mechanisms could occur at the same time, and hence the original catalytic nano-particle separates into two parts during growth. After removing the CNT arrays grown, a part of catalytic nanoparticle was left on the substrate, which can be used for subsequent CNT growth without additional catalyst. This repeated production of CNT array is called regrowth process, and the diameter of CNT can be reduced in accordance with the reduced catalyst size. By thermal annealing method, the initial $I_D/I_G$ ratio of 1.24 was improved to 0.41 in the fourth growth.

A supported Al layer has been reported to be critical in ensuring a high yield of SWNTs [12]. The Al layer promotes formation of very small bimetallic catalyst particles, consisting of Al and catalytic metal, for catalyzing the growth of SWNT [11, 12]. It has been known that during annealing in vacuum, metal catalyst is efficiently gotten away from the surface and trapped in a possibly liquid Al-Si layer to keep the activity for CNT growth. AlO$_x$ layer, which could be formed from Al layer by annealing in O$_2$ atmosphere, indeed
Figure 1: SEM images of CNT arrays grown after the (a) first, (b) second, and (c) third growth by the lift-off method. The length of CNT array is (a) 35, (b) 24 and (c) 25 μm. The insets show high-magnification SEM images.

promotes formation of thinner nanotubes as compared with other buffer layers [15].

In this paper, regrowth has been carried out by a custom-made PE-thermal CVD, and CNTs formed at each regrowth cycle have been characterized. Two kinds of treatments, lift-off and annealing, are used to remove the CNT arrays. The variation of the diameter and length of CNT arrays for each cycle is characterized and compared. It is found that the thermal annealing is preferred to obtain uniform SWNT arrays with high purity.

2. Experimental

Carbon nanotubes were grown by a custom-made PE-thermal CVD [16]. A 10 nm of Al film was coated on a 50 nm-SiO2/Si substrate by thermal evaporation. Then a 3 nm of Fe film was deposited as a catalyst by arc plasma method. Then, 80 sccm of H2 was exposed to the substrate at 700°C for 1 minute. For the CNT growth the flow rate of H2 and CH4 were 80 and 20 sccm, respectively. The total pressure was kept at 1.7 torr and the growth temperature was 800°C.

The regrowth was carried out using two different processes: lift-off method and thermal annealing method. In the former the CNT array was removed in acetone by an ultrasonic cleaner. In the latter the array was set in the heating furnace in atmosphere at 650°C for 1 hour. This oxidation treatment removed amorphous carbon on the catalyst as well as CNTs. The surface morphology was observed by field emission scanning electron microscopy (FESEM, Hitachi, S-4700) and the crystallinity of CNTs was examined using 633 nm Raman spectroscopy.

Through the thermal annealing process the substrate was heated to 650°C in a CVD chamber, and the Al layer melted into small droplets. Residual oxygen inside the chamber or the underlying SiO2 layer reacts with Al and stable AlOx clusters are formed [17]. During the annealing at high temperature, the AlOx was transformed from Al, which provides the support for the formation of Fe nanoparticles catalyzing the growth of SWNTs.

3. Results and Discussion

3.1. Lift-Off Process. Figures 1(a)–1(c) shows SEM images of CNT arrays grown by using lift-off treatment after the first, second and third growth, respectively. The lengths of CNT arrays are 35, 24, and 25 μm. The insets show magnified images. The diameters of CNTs, which are observed by transmission electron microscope (TEM) in Figures 2(a), 2(b), and 2(c), are 15.7 ± 7.1, 10.1 ± 4.4, and 7.9 ± 3.6 nm for the first, second and third cycles, and were shown in, respectively. It seems that catalytic activity of nano-particles was preserved after the lift-off process. Figure 3(a) shows a SEM image of the substrate after removing CNT arrays by the lift-off method. The array was completely removed and donut-structure was observed on the surface. It seems that the hole inside the donut corresponds to the footprint of
3.2. Thermal Annealing Process. Figure 5 shows SEM images of CNT array grown after the first, second and third growth. The lengths of CNT arrays are 35, 22 and 24 μm, respectively. The TEM images present the average diameters of CNTs are 15.7 ± 7.1, 7.8 ± 2.8, and 6.3 ± 2.4 nm for the first, second and third cycles, as shown in Figures 2(a), 2(d) and 2(e), respectively. Figure 3(b) shows the SEM image of the substrate after removal of CNT arrays by annealing. Uniform catalyst particles are isolated to each other on the substrate surface. From the result of successful regrowth, the catalytic
Figure 4: Raman spectra of CNTs at each cycle by the lift-off method.

Figure 5: SEM images of CNT array grown for the (a) first, (b) second and (c) third growth by annealing method. The length of CNT array is (a) 35, (b) 22 and (c) 24 μm. The insets are high-magnification images.
activity of nano-particles seems still alive for CNT regrowth and diameters are reduced after each regrowth cycle. The changes in the length of CNT arrays and growth cycle by the two treatments are shown in Figure 6(a).

Figure 7 shows Raman spectra of CNTs after each cycle. In Figure 7(a), a sharper G-band peak with higher intensity was observed as the growth cycle increased. The third growth cycle reaches a highest graphitic crystallization with the $I_D/I_G$ ratio of 0.22 from 0.5 grown by the first growth. The relationship between $I_D/I_G$ ratio and the growth cycles is shown in Figure 6(b). By using the lift-off treatment, the $I_D/I_G$ ratios after each cycle remain same (0.5–0.57), indicative of uniform CNT arrays in every stage of growth. On the other hand, the $I_D/I_G$ ratio through thermal annealing

**Figure 6:** (a) CNT array length, and (b) $I_D/I_G$ ratio as a function of growth cycle.

**Figure 7:** Raman spectra in (a) G-band and D-band, (b) RBM region of CNTs for three cycles growth by annealing method.
decreases with growth cycle. It indicates the crystallization of CNTs was improved by thermal annealing and regrowth process. The key reason for the improvement of crystallization lies in the reduced diameter of CNT by the particle-separated regrowth process, which correlates with the quantity of defect structures in CNT. Although the Al layer could be partially oxidized through the lift-off process, Fe nanoparticle has still high possibility to contact with metallic Al. It is very hard to synthesize SWNTs on catalyst-Al bimetals [19]. Residual amorphous carbon was removed through annealing process. In addition, Fe and uncompletely oxidized Al clusters were oxidized to Fe oxide and AlOx. The catalyst particle is probably in contact with AlOx rather than with metallic Al cluster. Figure 7(b) presents a RBM region of the Raman spectrum. For the first growth, there is no SWNT peak shown in the spectrum. The only peak around 280 cm\(^{-1}\), representing the formation of iron oxide [20], was observed in this spectrum. In the spectrum of the second growth, another sharp peak around 190 cm\(^{-1}\) was observed. This indicates that SWNTs were produced by regrowth process and that the diameter was calculated to 1.31 nm [21]. It should be noted that not only MWNT array but SWNT array was synthesized by the regrowth using thermal annealing method. Five peaks 190, 214, 249, 259 and 290 cm\(^{-1}\) are found in the third growth spectrum, corresponding to the diameter of 1.31, 1.16, 1.00, 0.96 and 0.86 nm, respectively. These values are smaller than 1.31 nm in the second growth. It indicates that the size of nanoparticles become smaller by each thermal annealing process on AlOx support layer. It should be also noted that the extraordinary narrow diameter of 0.86 nm was synthesized after the third growth, as clearly shown in the TEM image of Figure 2(f).

4. Conclusions
The CNT array was successfully grown by using a regrowth process without coating additional catalyst. By using lift-off treatment, the CNT array with uniform structure and length was regrown on the Al coated substrate. By using annealing treatment, SWNTs were found after the second growth due to reduction of catalytic particles on the AlOx support layer. After the third growth, extraordinary narrow diameter of 0.86 nm was synthesized through the third regrowth. Furthermore, the quality of CNTs was improved and extremely low \(I_D/I_G\) ratio of 0.22 was obtained.

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References

